

General Description

The WSP11N10T is the highest performance trench Dual N-Channel MOSFET with extreme high cell density, which provide excellent $R_{DS(ON)}$ and gate charge for most of the synchronous buck converter applications.

The WSP11N10T meet the RoHS and Green Product requirement, 100% E_{AS} guaranteed with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent Cdv/dt effect decline
- Green Device Available

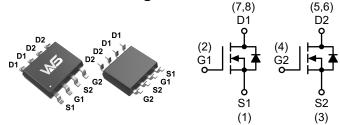
Product Summery

BV _{DSS}	R _{DS(ON)}	I _D	
100V	70mΩ	12A	

Applications

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

SOP-8L Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage	±20	V
I _D @T _C =25℃	Continuous Drain Current, V _{GS} @ 10V ¹	12	А
I _D @T _C =100℃	Continuous Drain Current, V _{GS} @ 10V ¹	6.0	А
I _{DM}	Pulsed Drain Current ²	35	А
EAS	Single Pulse Avalanche Energy ³	6.25	mJ
I _{AS}	Avalanche Current	5	А
P _D @T _A =25℃	Total Power Dissipation ⁴	1.5	W
T _{STG}	Storage Temperature Range	-55 to 150	$^{\circ}$ C
TJ	Operating Junction Temperature Range	-55 to 150	$^{\circ}$

Thermal Data

Symbol	Parameter		Max.	Unit
R _{0JA}	Thermal Resistance Junction-ambient ¹		85	°C/W
R _{θJC}	Thermal Resistance Junction-Case ¹		62	°C/W



Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	100			V	
$\triangle BV_{DSS}/\triangle T_{J}$	BV _{DSS} Temperature Coefficient	Reference to 25°C , I _D =1mA		0.098		V/℃	
D	Static Drain Source On Besistance ²	V _{GS} =10V , I _D =5A		70	95		
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =4.5V , I _D =3A		80	115	mΩ	
$V_{GS(th)}$	Gate Threshold Voltage	\/ -\/ -250\	1.2	1.8	2.5	V	
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	$V_{GS}=V_{DS}$, $I_D=250uA$		-5.52		mV/℃	
l	Drain-Source Leakage Current	V _{DS} =100V , V _{GS} =0V , T _J =25℃			1	uA	
I _{DSS}	Dialii-30dice Leakage Current	V_{DS} =100V , V_{GS} =0V , T_{J} =55 $^{\circ}$ C			100	uA	
I _{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm 20V$, V_{DS} =0V			±100	nA	
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		3.0		Ω	
Qg	Total Gate Charge (10V)			12			
Q _{gs}	Gate-Source Charge	V _{DS} =50V , V _{GS} =10V , I _D =10A		2.9		nC	
Q _{gd}	Gate-Drain Charge			1.5			
T _{d(on)}	Turn-On Delay Time			3.1			
Tr	Rise Time	V _{DD} =50V , V _{GEN} =10V ,		11.8			
T _{d(off)}	Turn-Off Delay Time	$R_G=6\Omega I_D=1A$,RL= 30Ω		4.5		ns	
T _f	Fall Time			15			
Ciss	Input Capacitance			1055			
C _{oss}	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		58		pF	
C _{rss}	Reverse Transfer Capacitance			42			

Guaranteed Avalanche Characteristics

Symbol	Parameter Conditions		Min.	Тур.	Max.	Unit
EAS	Single Pulse Avalanche Energy ⁵	V _{DD} =50V , L=0.5mH , I _{AS} =5A	3			mJ

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current ^{1,6}	V =V =0V Force Current			11	Α
I _{SM}	Pulsed Source Current ^{2,6}	V _G =V _D =0V , Force Current			30	Α
V_{SD}	Diode Forward Voltage ²	V _{GS} =0V , I _S =5A , T _J =25℃			1.1	٧
t _{rr}	Reverse Recovery Time	15 54 WW 40044 T - 05°C		21		nS
Q _{rr}	Reverse Recovery Charge	∏F=5A , dl/dt=100A/μs , T J=25℃		25		nC

Note

- 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, t<10 sec.
- 2.The data tested by pulsed , pulse width $\leqq 300 us$, duty cycle $\leqq 2\%$
- 3. The EAS data shows Max. rating . The test condition is V_{DD} =50V, V_{GS} =10V,L=0.5mH, I_{AS} =5A
- 4.The power dissipation is limited by 150 $^{\circ}\mathrm{C}$ junction temperature
- 5. The Min. value is 100% EAS tested guarantee.
- 6. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.



Typical Characteristics

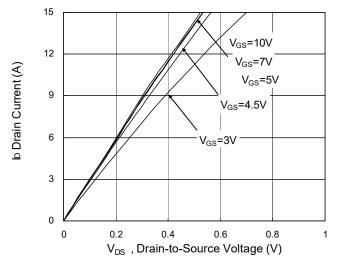


Fig.1 Typical Output Characteristics

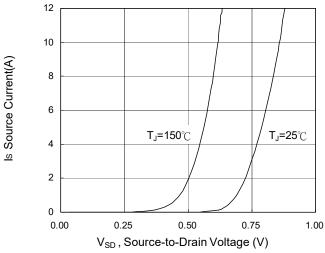


Fig.3 Forward Characteristics Of Reverse

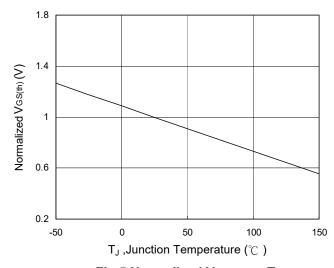


Fig.5 Normalized $V_{\text{GS(th)}}$ vs. T_{J}

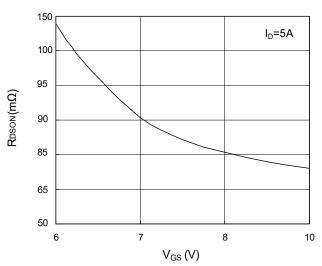


Fig.2 On-Resistance vs. Gate-Source

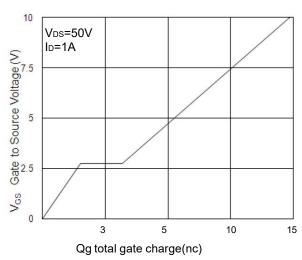


Fig.4 Gate-Charge Characteristics

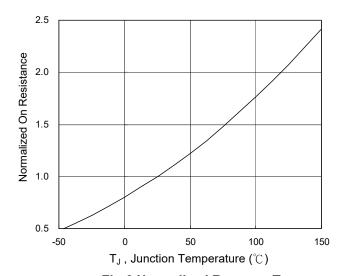
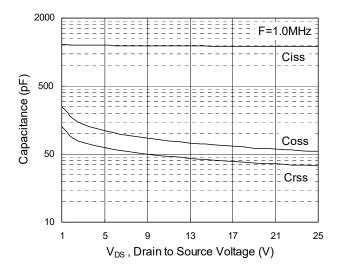


Fig.6 Normalized R_{DSON} vs. T_J





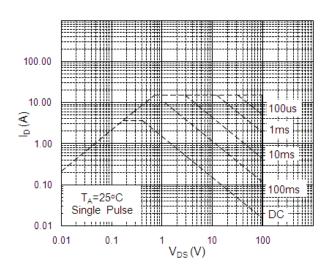


Fig.7 Capacitance

Fig.8 Safe Operating Area

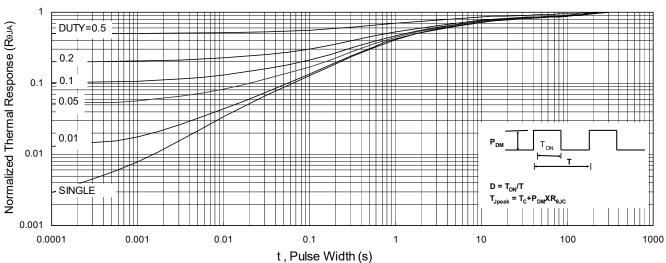


Fig.9 Normalized Maximum Transient Thermal Impedance

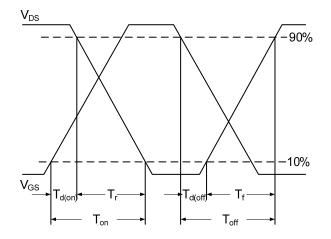


Fig.10 Switching Time Waveform

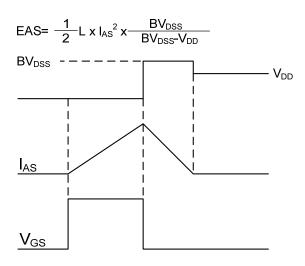
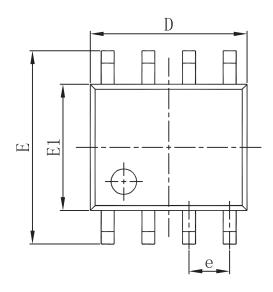
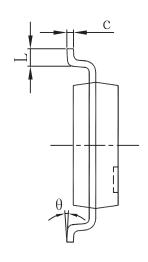


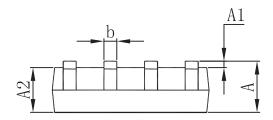
Fig.11 Unclamped Inductive Switching Waveform



Packaging information







Symbol	Dimensions In Millimeters		Dimensions	In Inches	
	Min	Max	Min	Max	
A	1. 350	1.750	0.053	0.069	
A1	0. 100	0. 250	0.004	0.010	
A2	1. 350	1. 550	0. 053	0.061	
b	0. 330	0. 510	0. 013	0. 020	
С	0. 170	0. 250	0.007	0.010	
D	4.800	5. 000	0. 189	0. 197	
e	1.270 (BSC)		0.050 (BSC)		
Е	5. 800	6. 200	0. 228	0. 244	
E1	3. 800	4. 000	0. 150	0. 157	
L	0.400	1. 270	0.016	0.050	
θ	0°	8°	0°	8°	



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